



Evaluation of the X-ray SOI pixel detector with on-chip ADC

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HSTD13@Vancouver

Outline

Introduction

- X-ray astronomy

- Concepts of future X-ray detector & XRPIX

Results of evaluations

- Unit test of the on-chip ADC

 - Integral non-linearity

 - Differential non-linearity

 - Noise from on-chip ADC

- XRPIX end-to end test

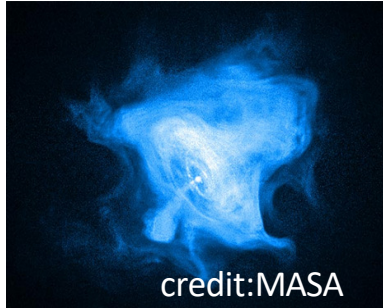
 - obtain X-rays spectrum from XRPIX

X-ray astronomy

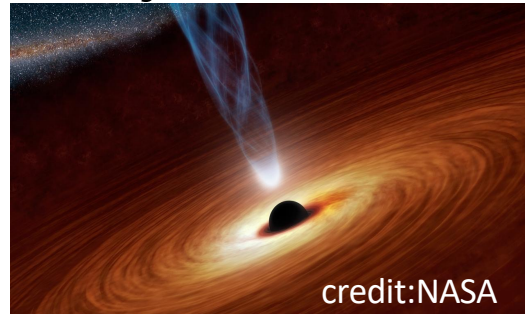
We can study high-energy physics through X-ray observations

Example : High energy celestial objects

Neutron stars



Vicinity of Black holes



Current standard X-ray detector : CCD

Pros : Energy resolution : 150 eV @ 6 keV

Good spatial resolution : 20 ~ 30 μm

Cons : Time resolution : several seconds

➤ unsuitable for celestial objects rotating in seconds

Concepts of future X-ray detector

Energy range : 0.5 – 80 keV

adopted **Si sensor (<20 keV)** and **CdTe sensor (>20 keV)**

➤ capable of **wide-band** X-ray research

Observation targets : **High energy** celestial objects

Low background above 10 keV

➤ Reduce non-X-ray events by **active shields**
capable of **low luminosity** celestial objects

Good time resolution ~ a few μ s

Future Si detector's Requirements

$\Delta E < 140$ eV @ 6 keV

It catches X-rays less than 20 keV

Time resolution ~ a few μ s

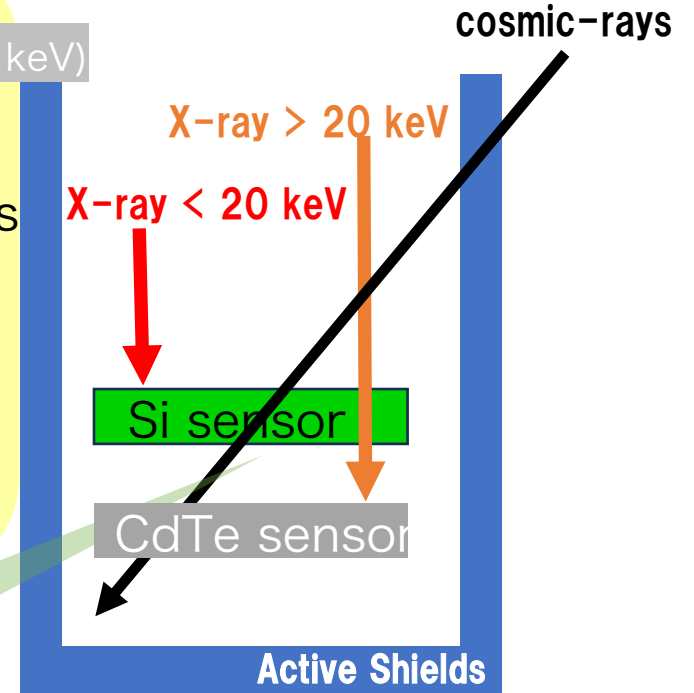


image of Wide-band X-ray Imager

This talk theme

Future Si detector **XRPIX**

Future X-ray detector : XRPIX

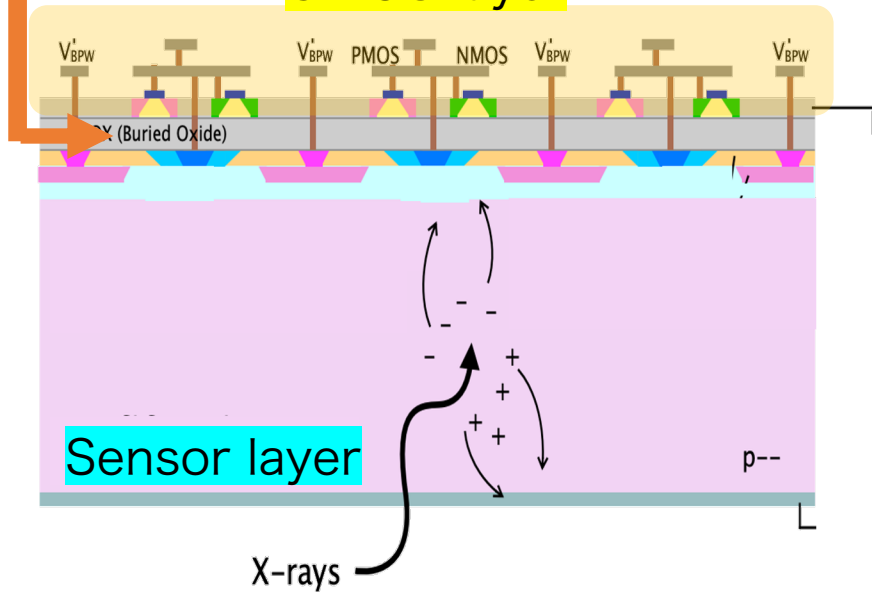
XRPIX is the **new** X-Ray detector made with SOI technology

trigger function
measure the moment when X-rays hit

➔ Combine CMOS Layer and Sensor

SiO₂ (Insulation layer)

CMOS layer



Good time resolution
each pixel has trigger function
▶ Time resolution < 10 us

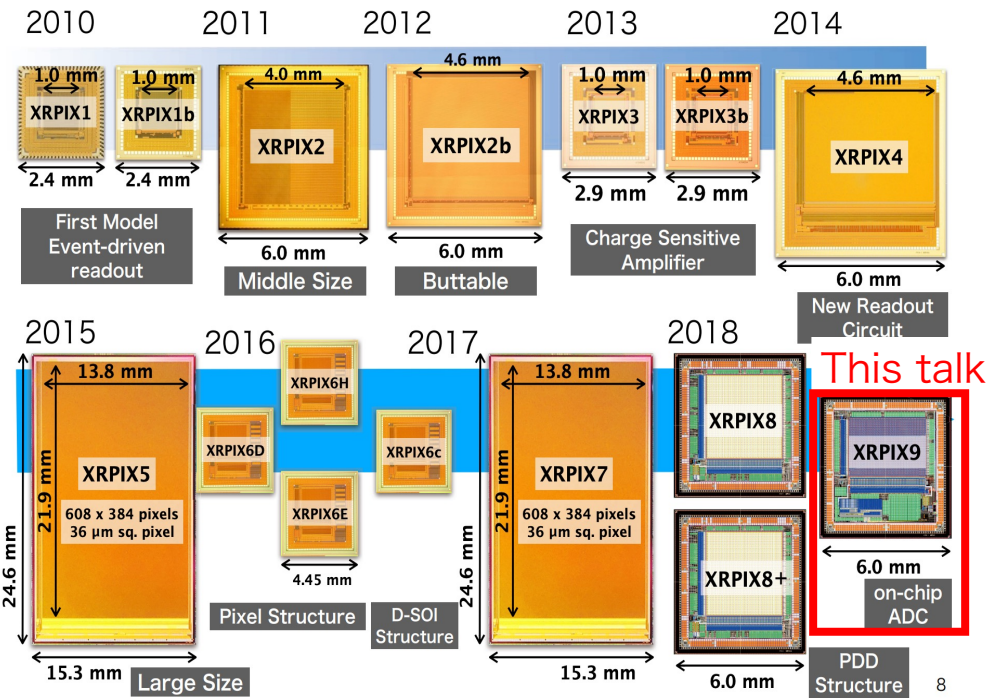
Energy resolution
 $\Delta E < 300$ eV at 6 keV
▶ Goal : $\Delta E < 140$ eV at 6 keV

Thick sensor layer
▶ High detection efficiency for X-rays

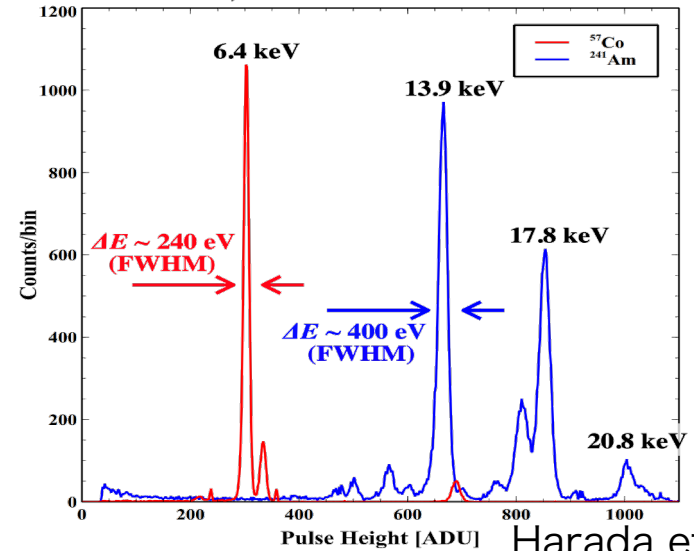
It will be installed on X-ray satellites

XRPIX's current status

We've been researching and developing



XRPIX6E
FWHM~240 eV at 6.4 keV

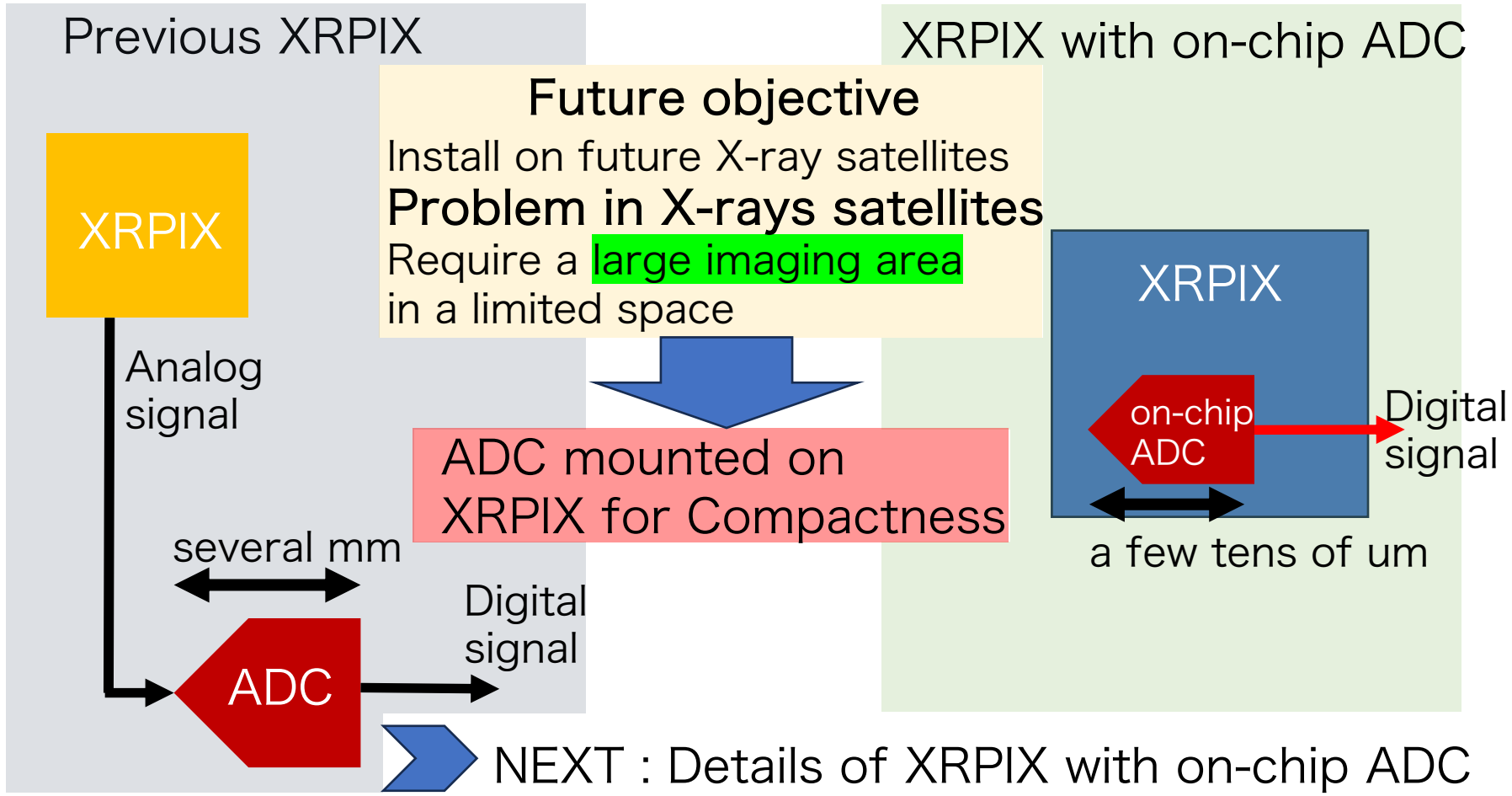


Harada et.al 2019

Sensor : Good spectral performance

We are currently working on digitalization

Previous designs and problems



XRPIX with on-chip ADC

XRPIX9

The first XRPIX to output **digital signal**

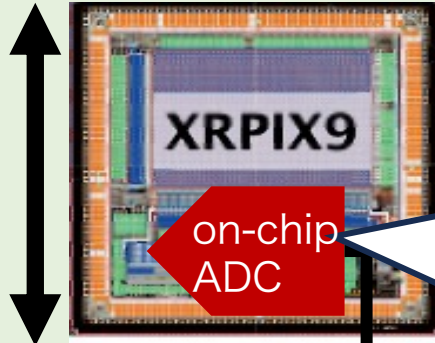
pixel area
36 μm \times 36 μm

Sensor layer \sim 300 μm

capable of
wide-band detection
1.0 - 40 keV

XRPIX9 on-chip ADC

6.0 mm



Digital
signal

Type : Cyclic ADC

High speed (6 μs)

Small size (20 μm)

➤ Advantages

Number of bits : 14 bits

Voltage range : 0.4-1.5 V

Total units : 16 units

➤ 1 column has 2 ADC

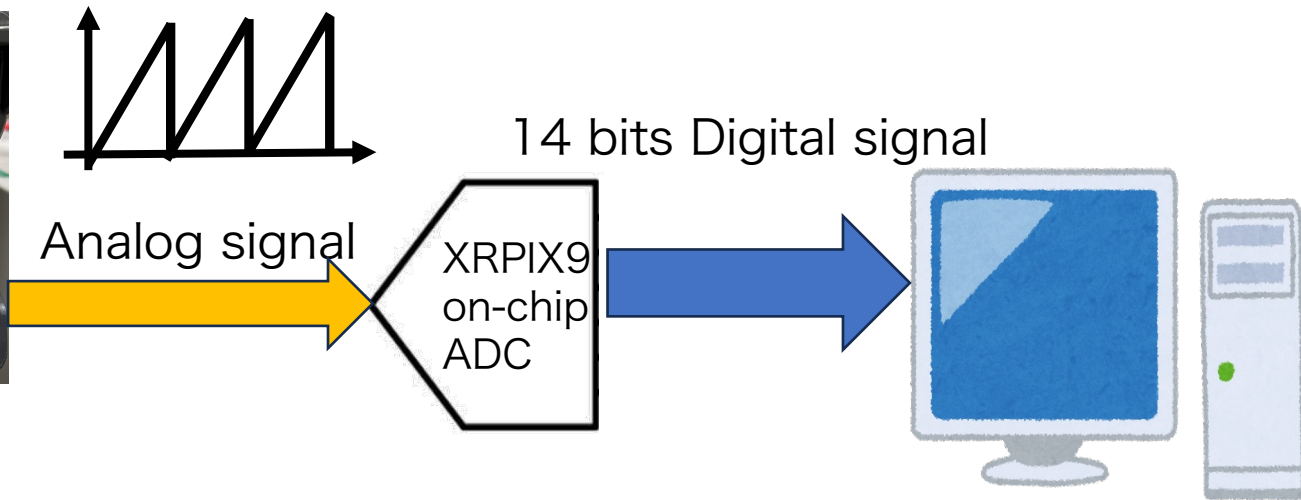
Goal : Evaluate the performance of its **on-chip ADCs** and inspect that **XRPIX9** has the same performance of **previous XRPIX**

Unit test of the on-chip ADC

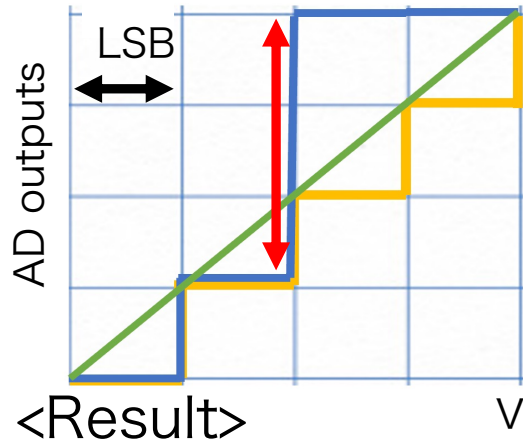
Input ramp wave or constant voltage into ADC



Function generator



Result 1: Integral Non-Linearity (INL)



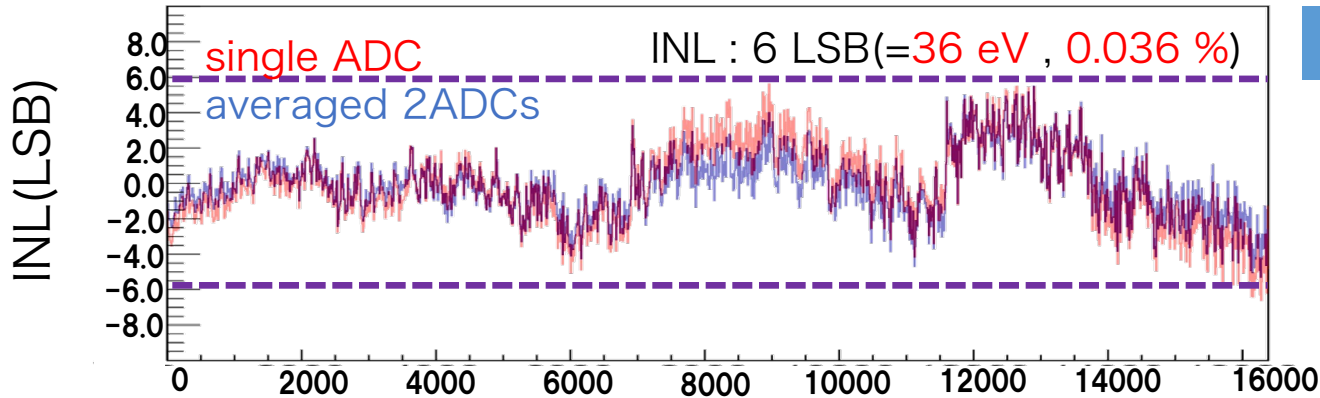
Input ramp wave into on-chip ADC

Ideal ADC steps one at a time

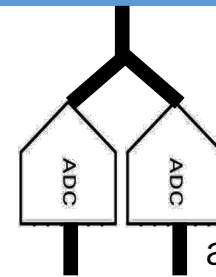
Actual ADC : Vertical deviation occurs

Methods :

Fitted actual ADC outputs with straight line
calculated residuals between the line and ADC outputs



Pixel



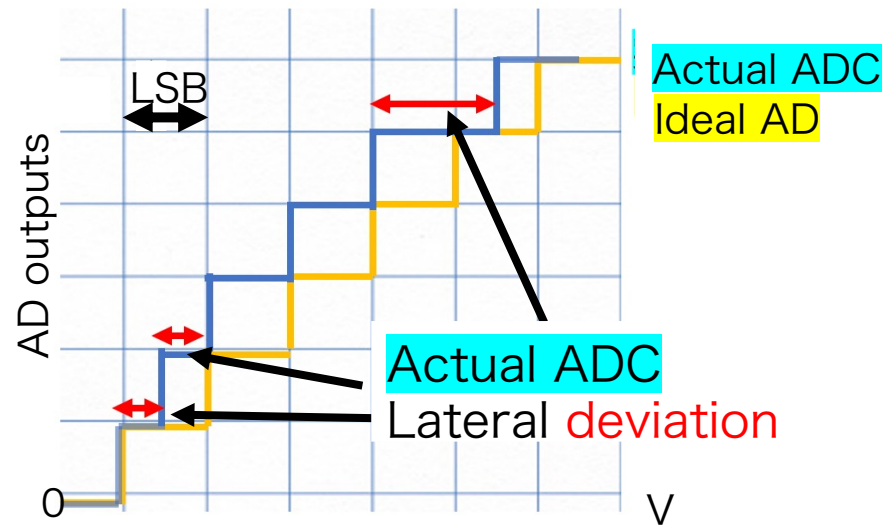
2ADC are used for 1 column

averaged 2ADCs

ADC Outputs

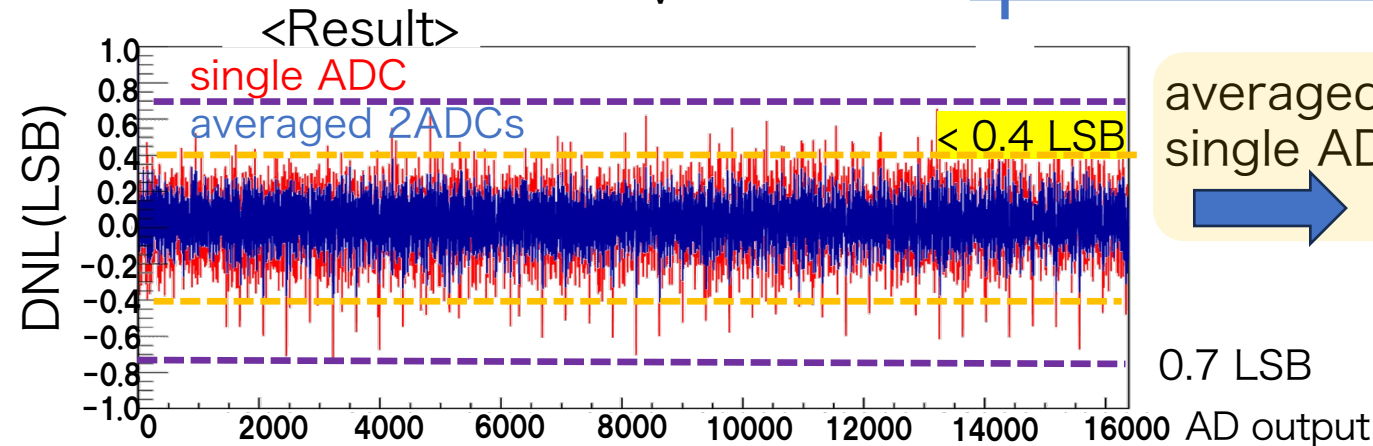
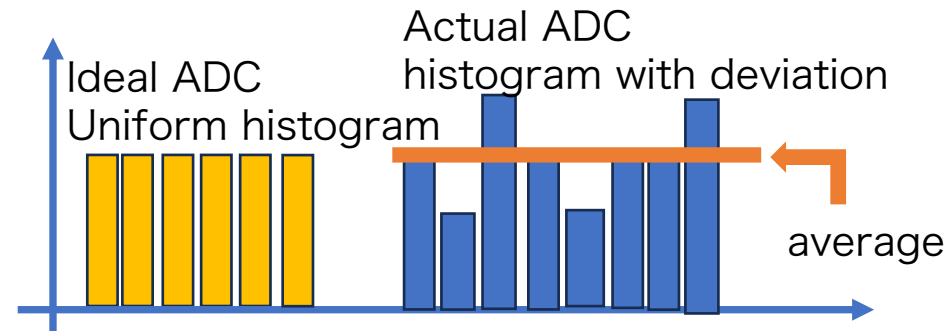
Negligible level for resolution 300 eV

Result2:Differential Non-Linearity (DNL)



Methods :

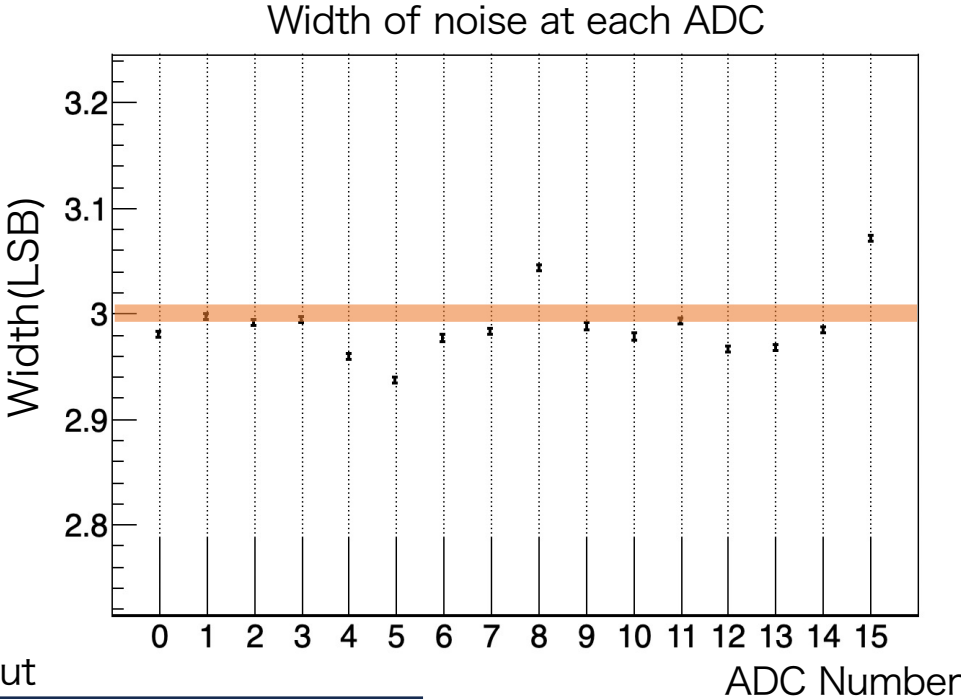
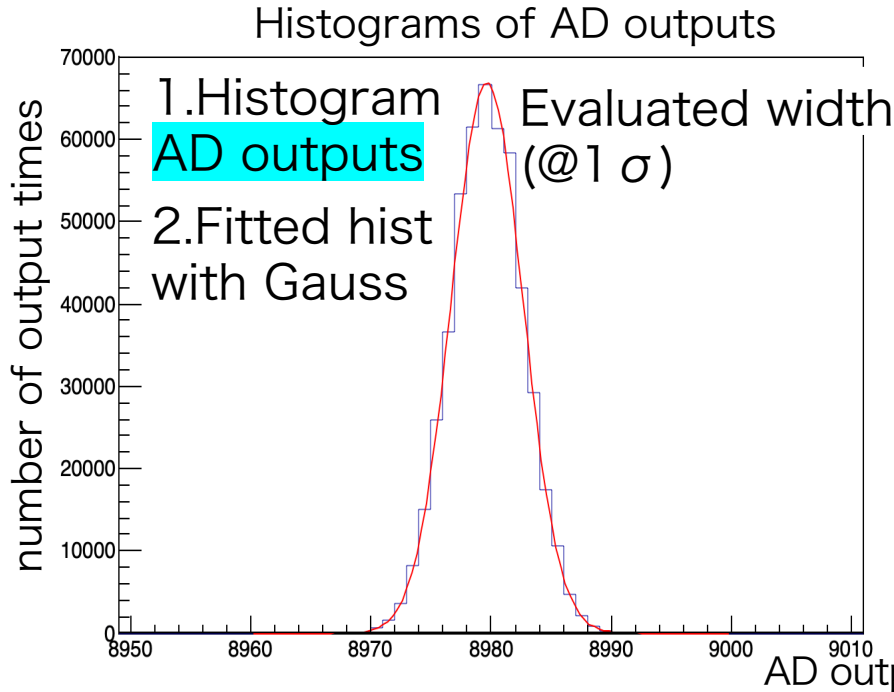
Histogram the number of AD outputs
Evaluate deviation from ideal ADC



averaged ADC's DNL < 0.4 LSB
single ADC's DNL < 0.7 LSB
➡ NO MISSING CODE

Result3:Noise

Methods : Input constant voltage into on-chip ADC

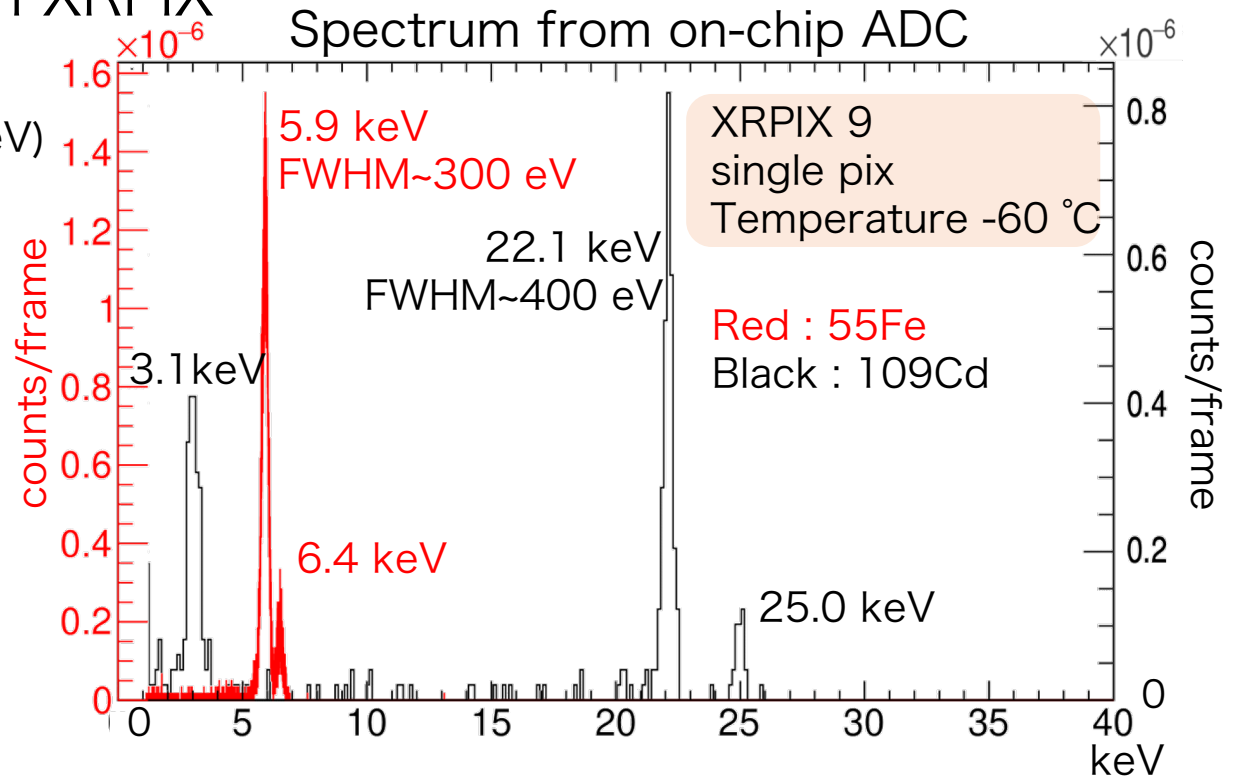
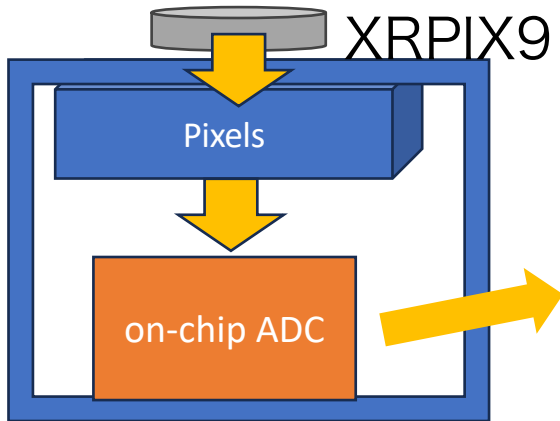


Noise width ~ 3 LSB (= 5 e)
→ Negligible level for 300 eV

XRPIX9 end-to-end test

➤ Irradiated X-rays on XRPIX

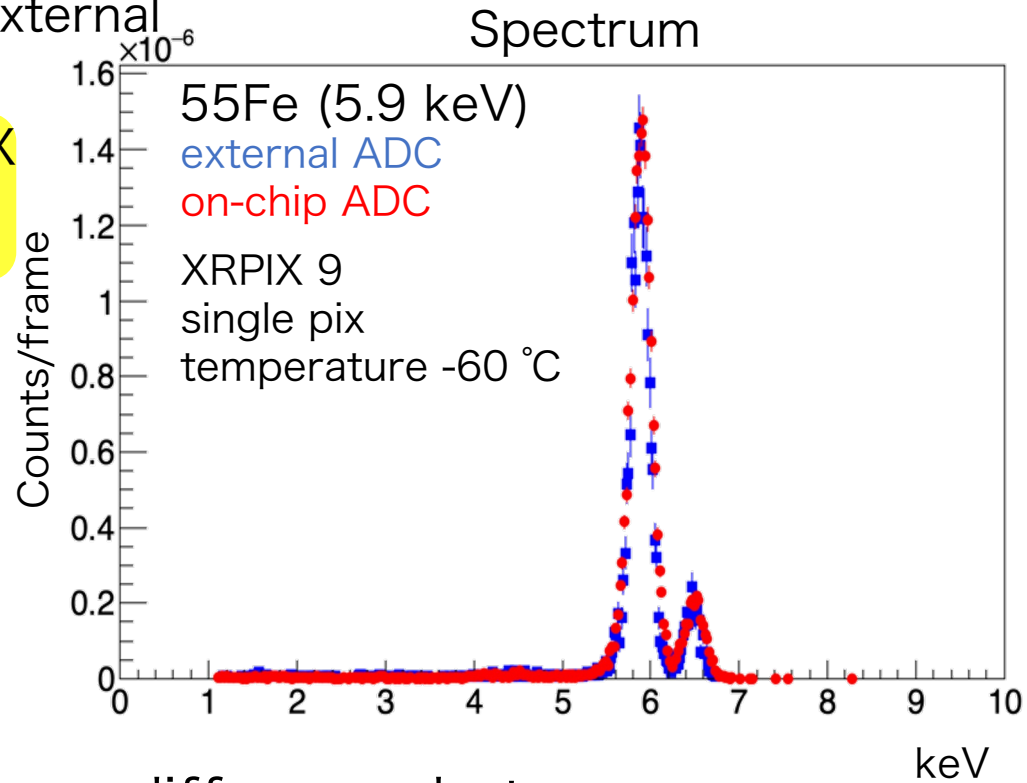
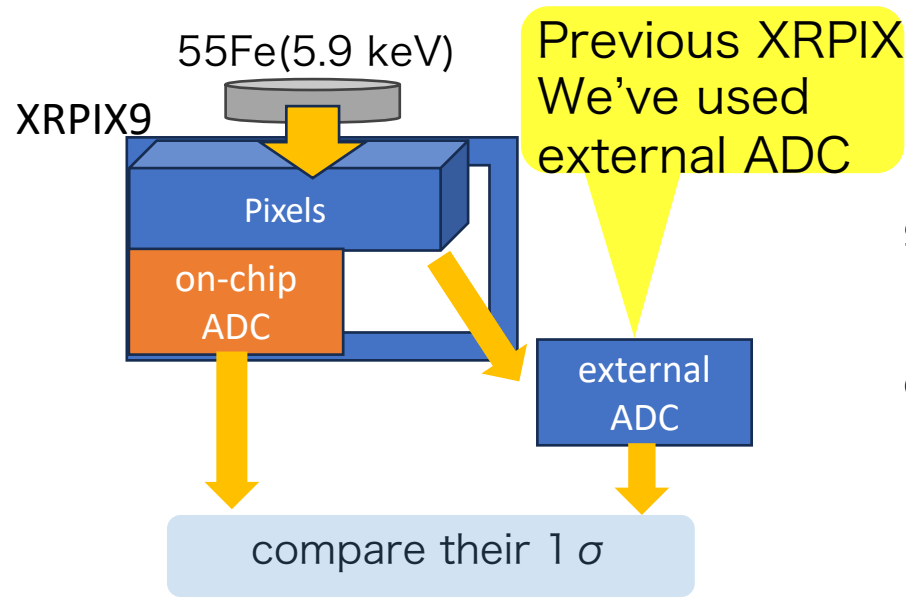
^{55}Fe (5.9 keV) & ^{109}Cd (22.1 keV)



Successfully obtained spectra from on-chip ADC

Comparison with external ADC

➤ Comparison on-chip ADC with external



➤ investigate performance difference between external ADC and on-chip ADC

on-chip ADC vs external ADC

➤ Fitted X-ray spectrum with gaussian and compared these width of 1σ

Most of plots are along

$$\sigma_{\text{on chip}} = \sigma_{\text{external}}$$

Almost the same performance
But plots are slightly above it



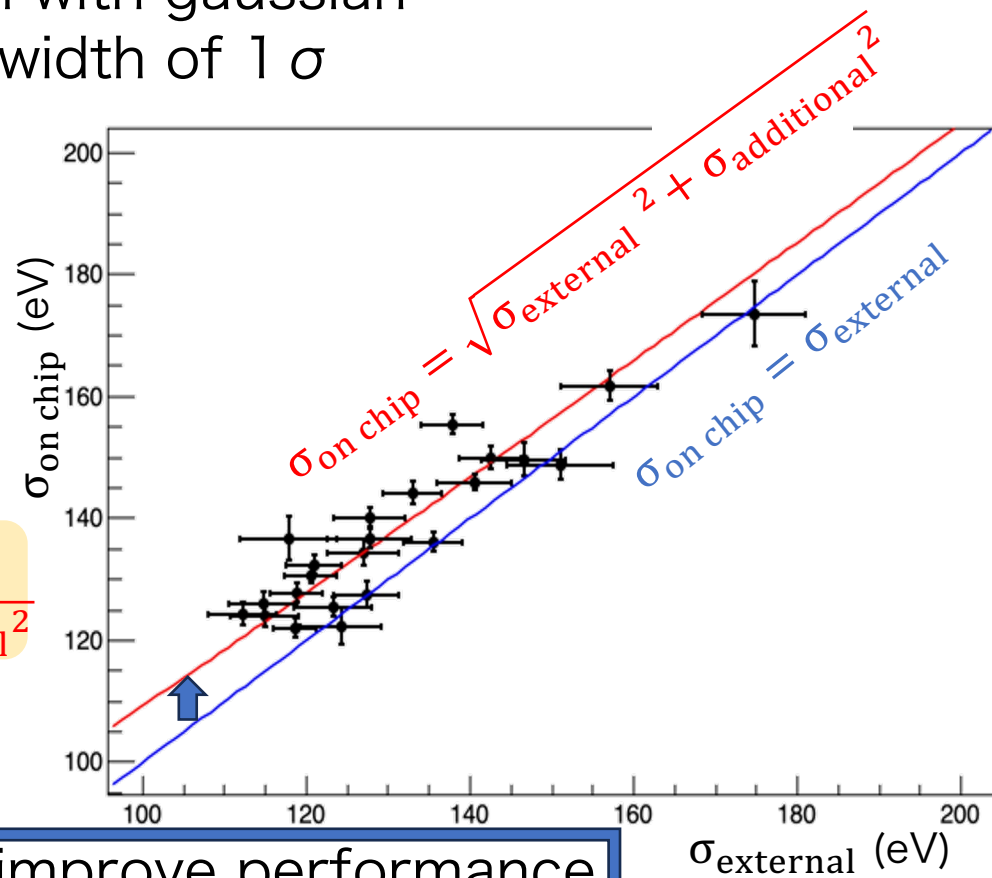
To go over the noise of on-chip ADC

Fitted plots with $\sqrt{\sigma_{\text{external}}^2 + \sigma_{\text{additional}}^2}$

Results : contains

unrecognized noise of 45 eV

Future task : Evaluate noise & improve performance



Summary

Objective

XRPIX aims to be installed on future X-ray satellites as detector

➡ Future task: **Digitalization**

Detector needs to be compact ➡ We developed **on-chip ADC**

Result : Unit test of on-chip ADC

1. Integral Non-Linearity: **0.036 % (6 LSB , 36 eV)**
2. Differential Non-Linearity: **NO MISSING CODE (DNL < 0.7 LSB)**
3. Noise : **3 LSB (5 e)**

Result : XRPIX9 end to end test

We **successfully** obtained spectrum from on-chip ADC
(FWHM@5.9 keV ~ 300 eV , FWHM@22.1 keV ~ 400 eV)

No crucial differences between on-chip and external

Problem : Noise(1σ) = 45 eV ➡ Future task & improve it

Back up

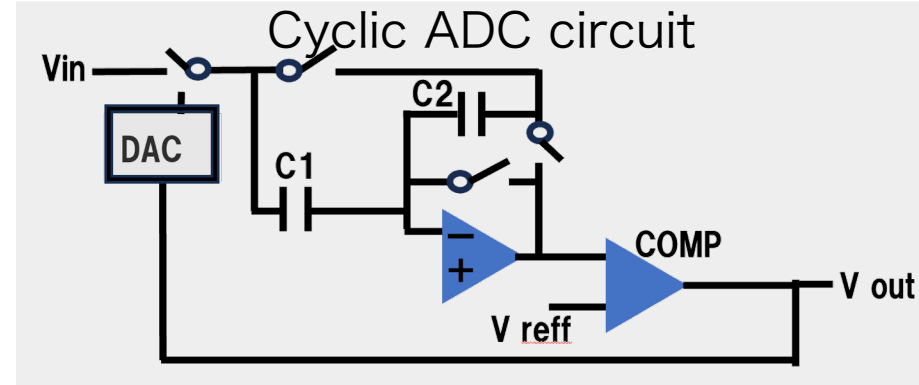
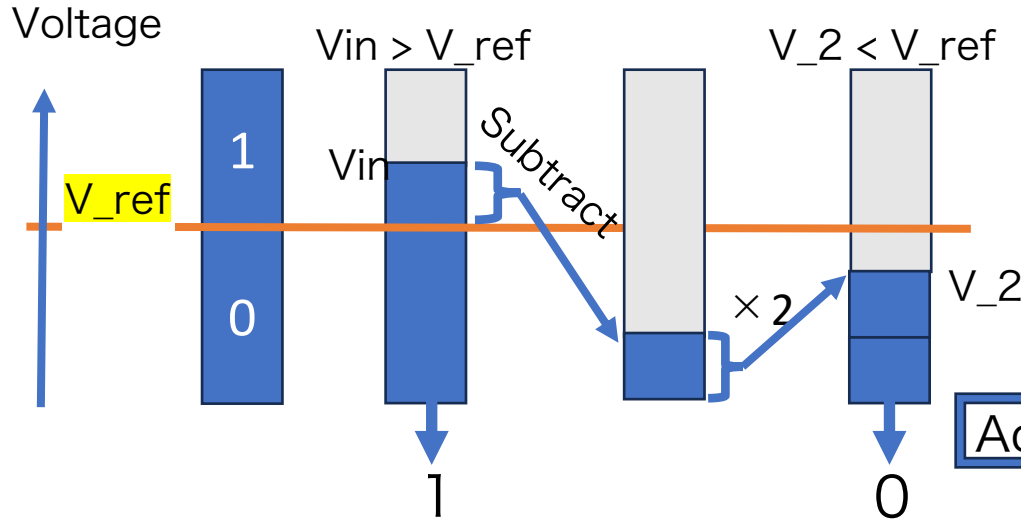
Cyclic ADC

XRPIX9 adopted cyclic ADC

▶ How to work cyclic ADC

Process of AD conversion

Digital output XXXX — LSB
X — MSB



1. compare V_{in} with V_{ref}
 If $V_{in} > V_{ref} \rightarrow 1 = \text{MSB}$

2. Subtract V_{ref} from V_{in}
 & $V_2 = 2 \times (V_{in} - V_{ref})$
 compare V_2 with V_{ref}
 If $V_2 < V_{ref} \rightarrow 0 = \text{MSB-1}$

3. Repeat process for 14 times
 $\rightarrow 14$ bit Cyclic ADC

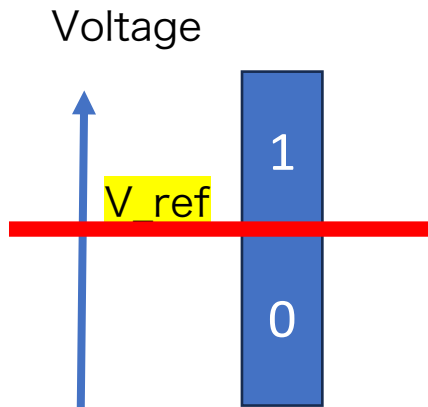
Advantages : small size and high speed

1.5 bit cyclic ADC

Actually, We have used 1.5 bit ADC.

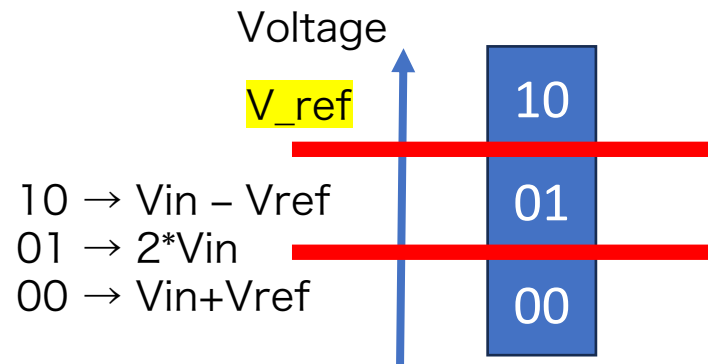
1 bit ADC

So far, ADC to determine 0 or 1



1.5 bit ADC

Bit is determined by 00, 01 or 10

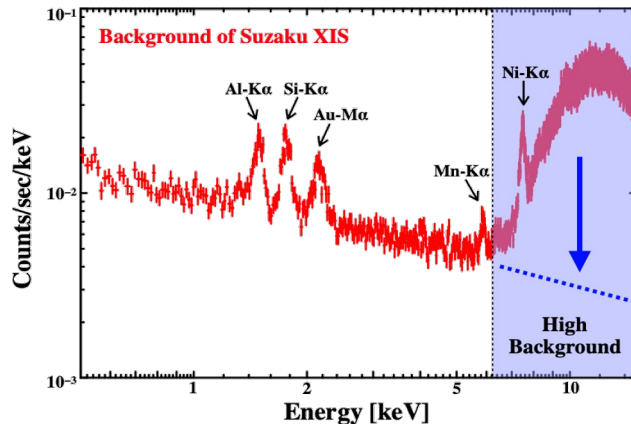
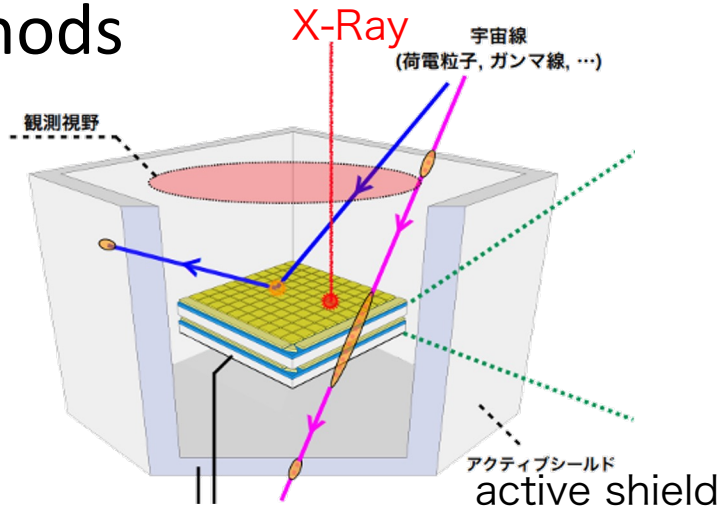
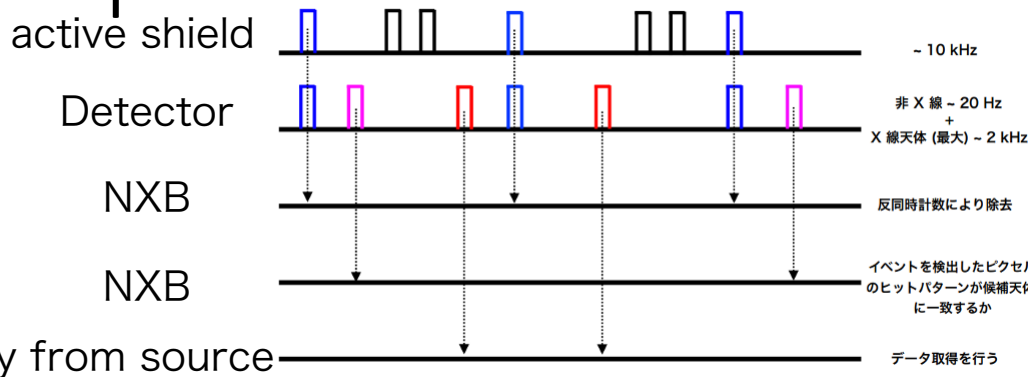


Advantages of Future satellite

1. Low background(from CXB)



introduction of anti-coincidence methods



アクティブシールドは10 kHzで反応
時間分解能10 usが必要

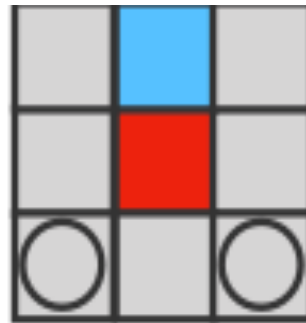
最終的にこの程度まで低減

Pixel pattern

single pixel event



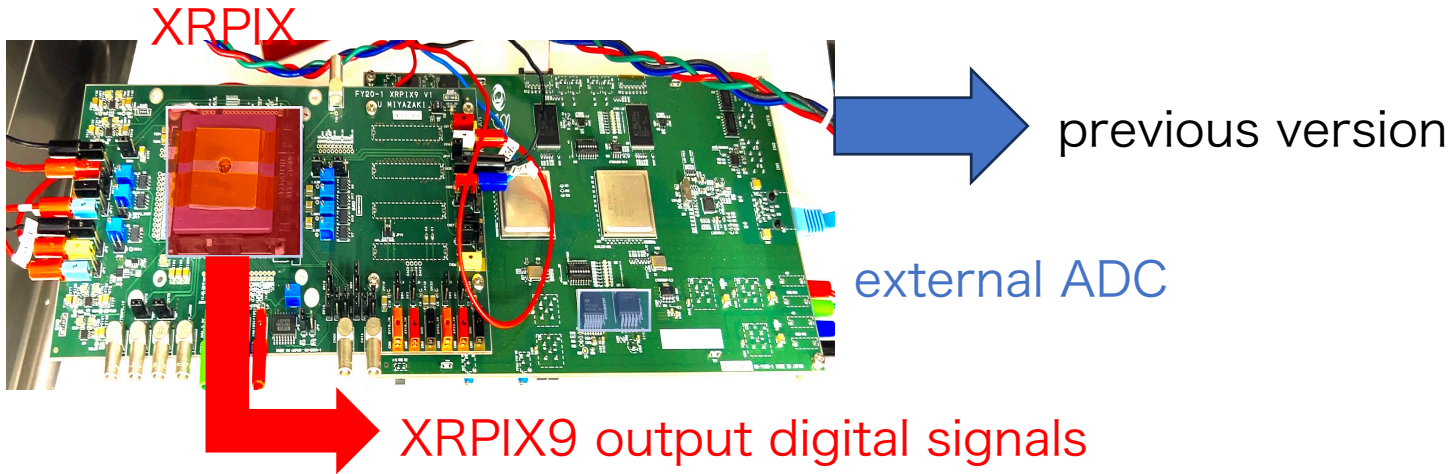
double pixel event



4 pixel event

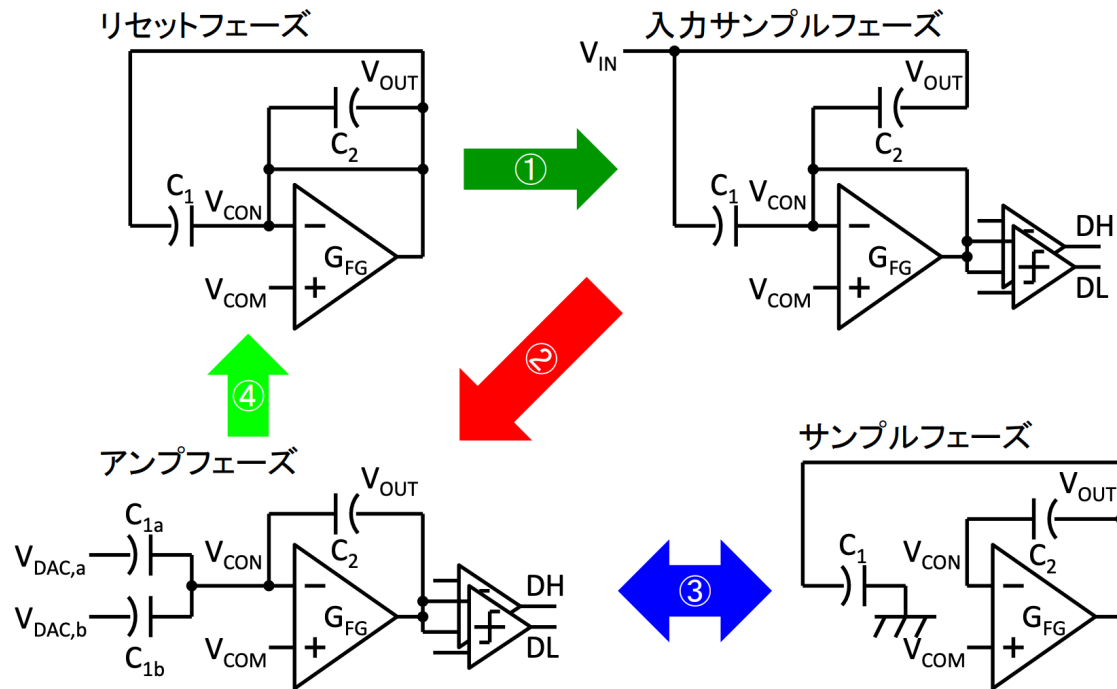


Purpose of degitalization



How to work ADC

通常動作

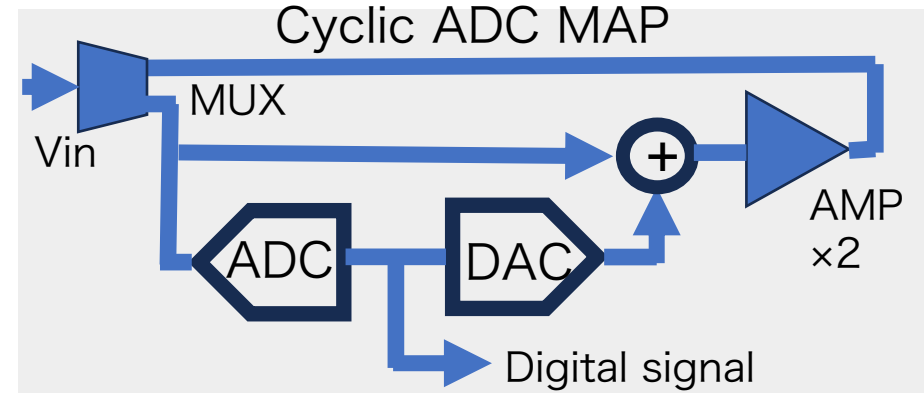
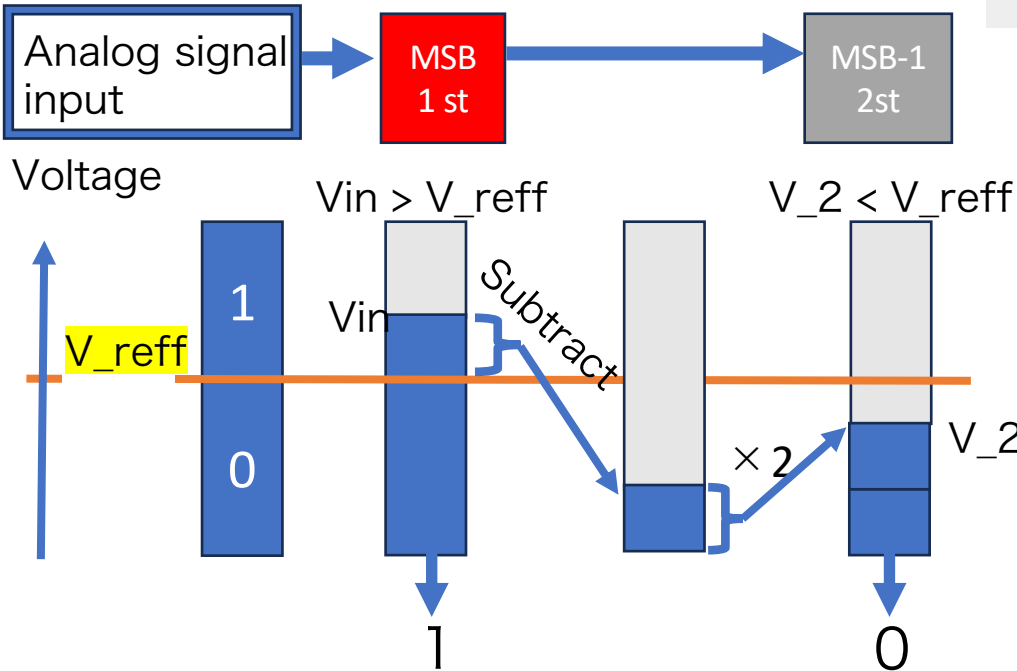


About ADC

▶ How to work cyclic ADC

Process of AD Conversion

Digital Output $\overbrace{XXXX}^{\text{MSB}} \text{---} \text{LSB}$



1. compare V_{in} with V_{ref}
If $V_{in} > V_{ref} \rightarrow 1 = \text{MSB}$
2. Subtract V_{ref} from V_{in} & $V_2 = 2 \times (V_{in} - V_{ref})$
compare V_2 with V_{ref}
If $V_2 < V_{ref} \rightarrow = \text{MSB-1}$
3. Repeat process for 14 times
 $\rightarrow 14$ bit Cyclic ADC

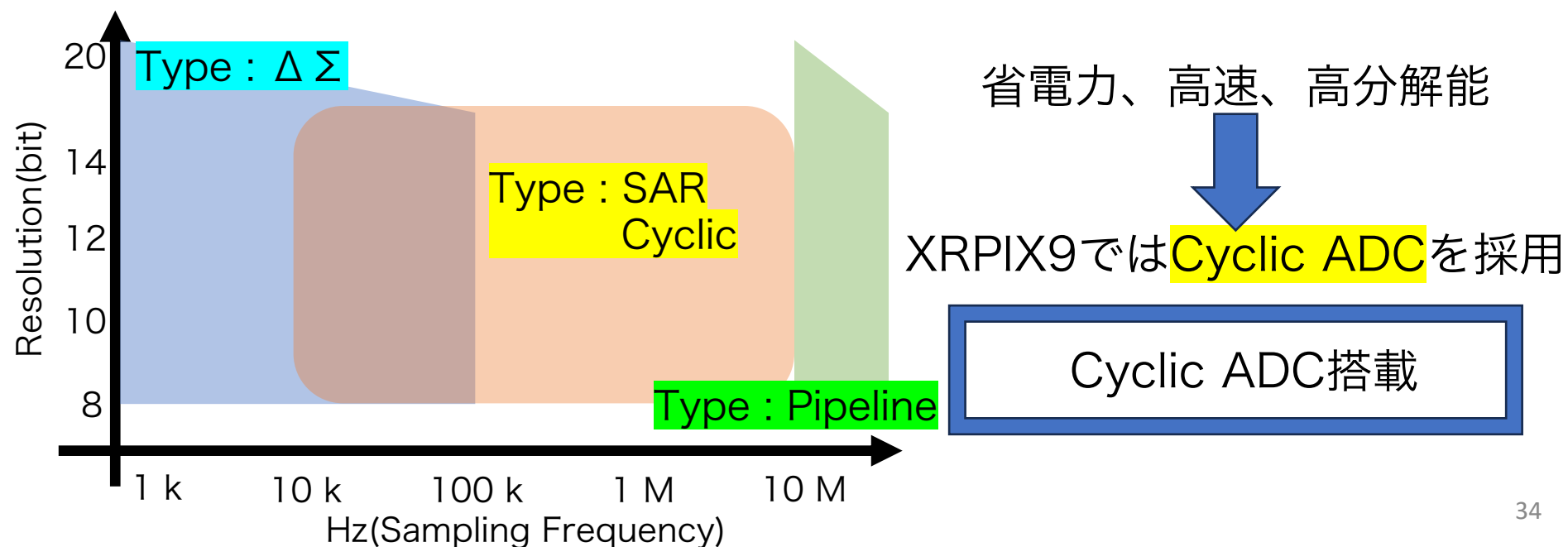
Purpose of Digitalization

X-rays create electron pairs

電圧に変換される

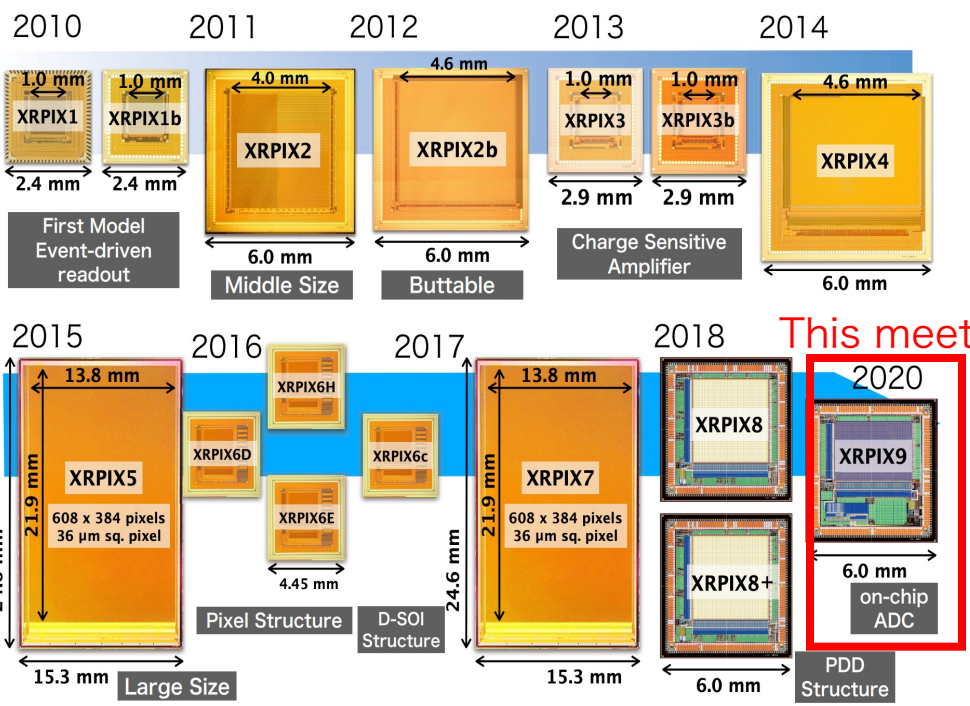
しかし、衛星搭載を目指していることや

スペクトル解析などデータ解析にはデジタル化が必須となる→ADCの利用

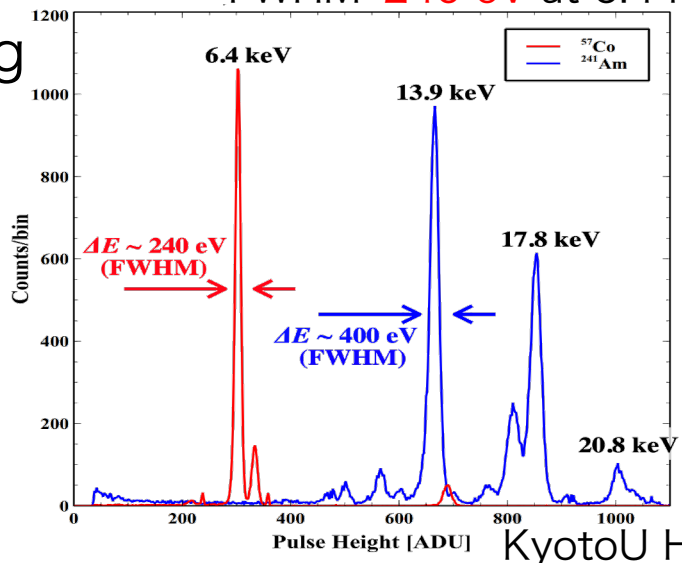


XRPIX's current status XRPIX6E FWHM~240 eV at 6.4 keV

We've been researching and developing



From Ayaki Takeda



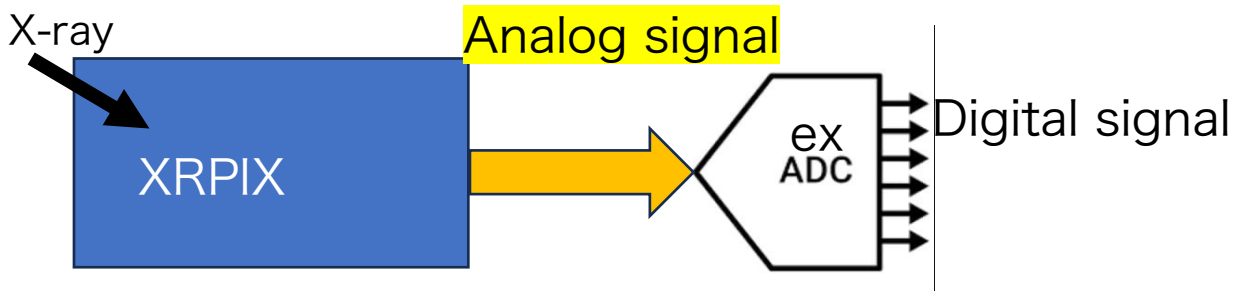
KyotoU Harada

Sensor : Good spectral performance

Future task : Digitalization

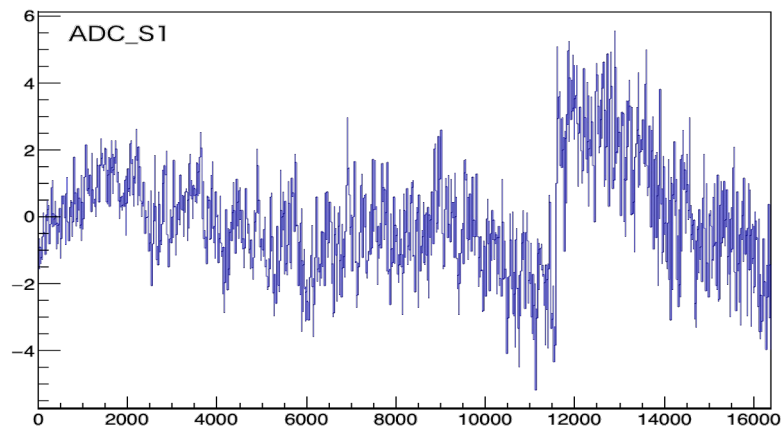
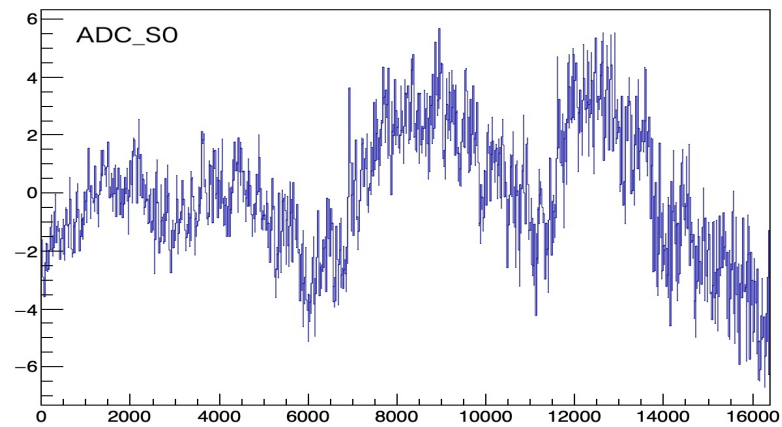
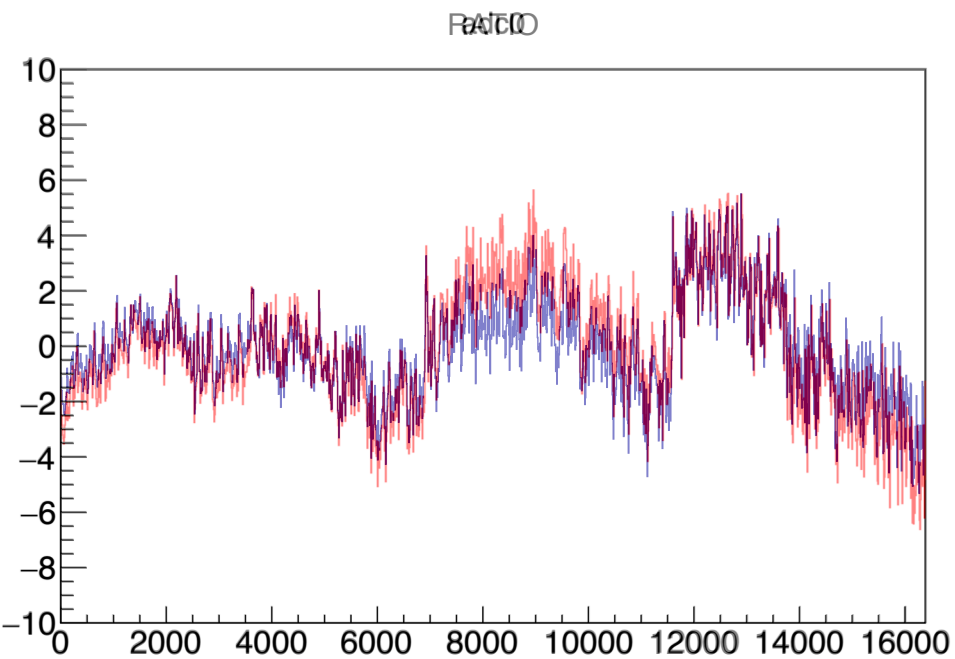
Purpose of on-chip ADC

Previous XRPIX : Converts **analog signals** with external ADC

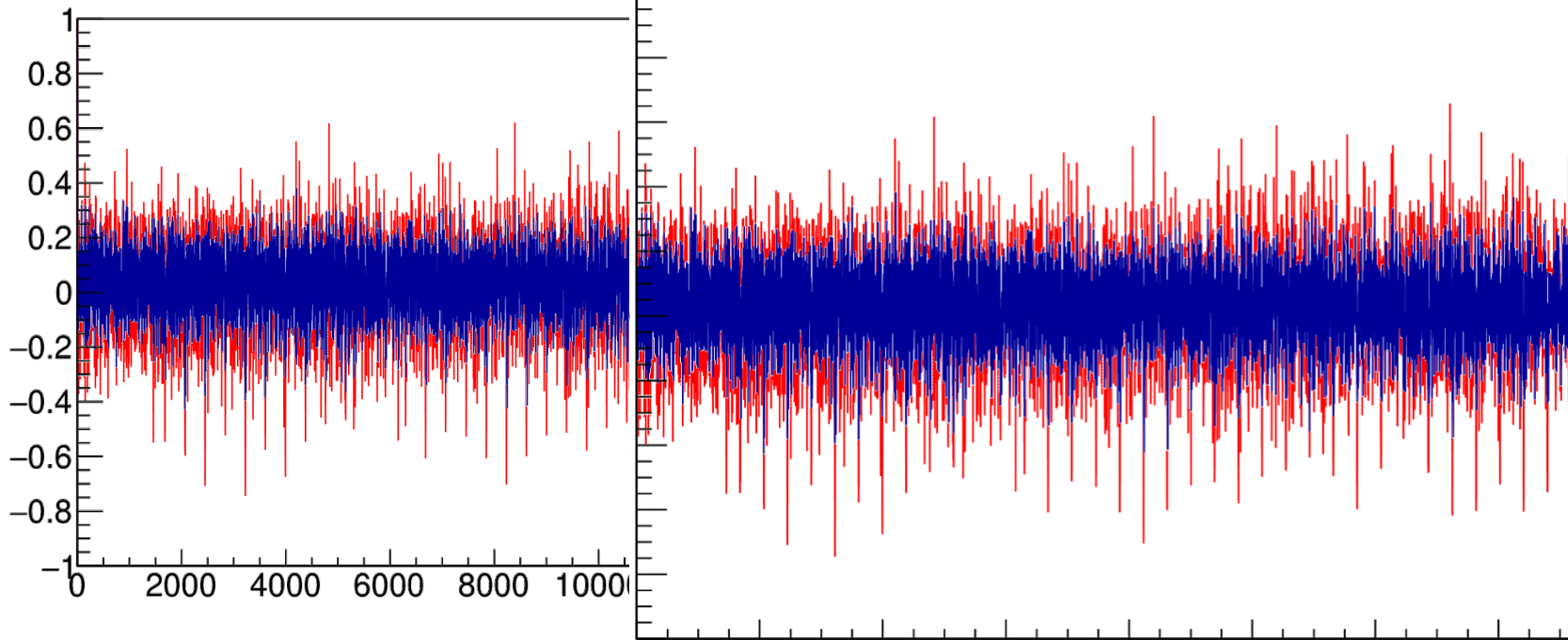


Problem : X-ray satellites require a large imaging area in a limited space

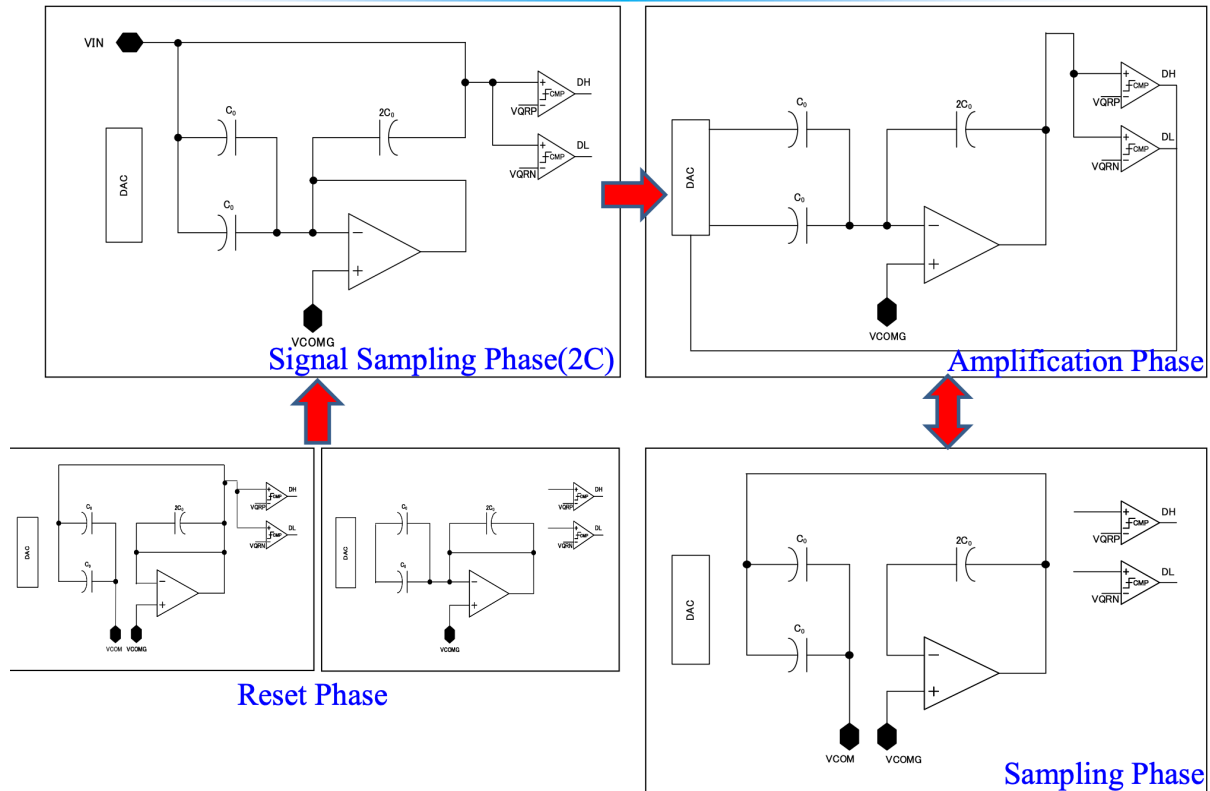
ADC mounted on XRPIX for compactness(**on-chip**)



RATIO



ADC readout process

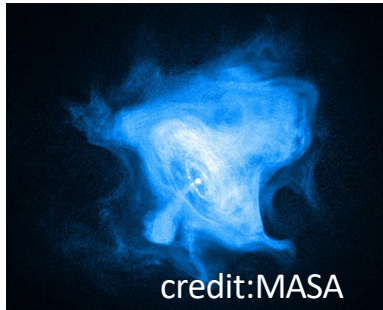


X-ray astronomy

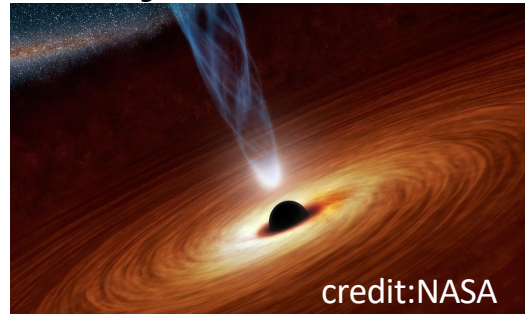
We can study high-energy physics through X-ray observations

Example : High energy celestial objects

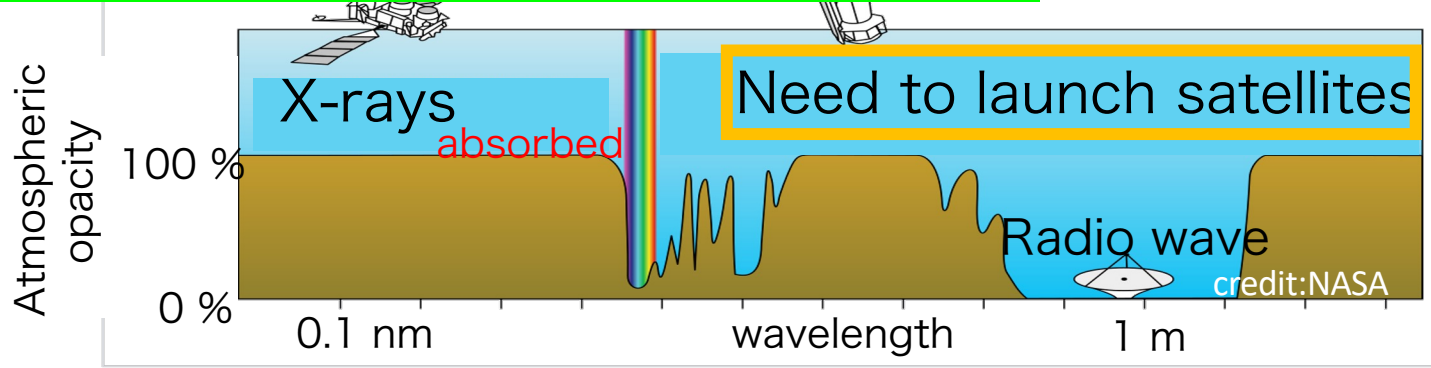
Neutron Stars



Vicinity of Black Holes

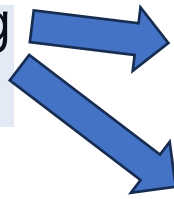


X-rays are fairly absorbed in atmosphere



Purpose of Digitalization

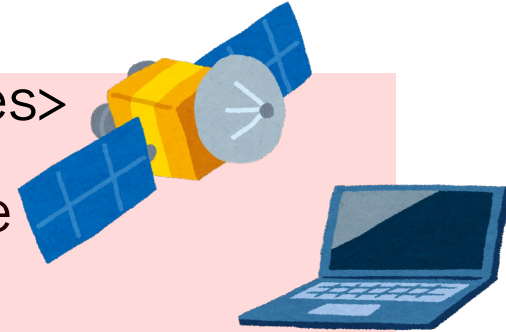
X-ray signals are Analog



<Future Objectives>

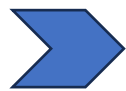
Install on Satellite

X-ray spectrum Analysis etc...



Digitalization is necessary for these objectives
Also , **ADC** is necessary for Digitalization

Digital-Analog Converter



NEXT : About ADC & How does it work ?

Purpose of on-chip-ADC

Previous XRPIX



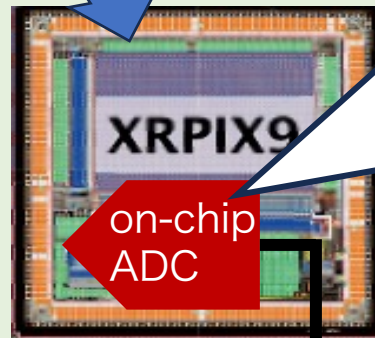
Analog signal



Digital signal

ADC mounted on XRPIX for Compactness

XRPIX9 on-chip ADC



Type : Cyclic ADC
Low Energy Consumption
High Speed (50 MHz)
Small Size (20 um)
➡ Advantages
Number of bits : 14 bits
Voltage range : 0.4-1.5 V
Total Units : 16 units

Digital signal

Goal : Evaluate on-chip ADC

<Problem in X-rays Satellite>
Require a large imaging area
in a Limited space

Future X-Ray satellite and detector

<Concepts of future X-ray satellite>

Energy range : 0.5 - 80 keV (Wide band)

Observation targets : Black hole, Neutron star...

Low non-X-ray background above 10 keV

Good time resolution ~ a few μ s

image:FORCE

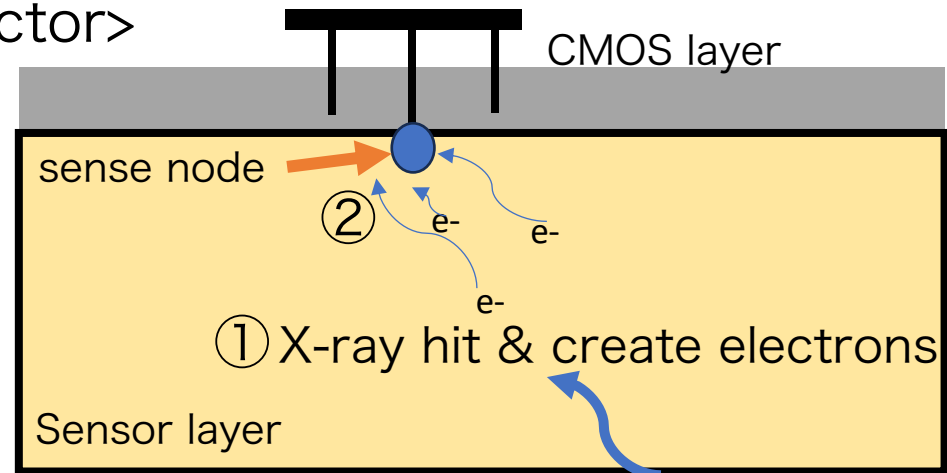


<How to work CMOS X-ray detector>

1. X-rays create electrons

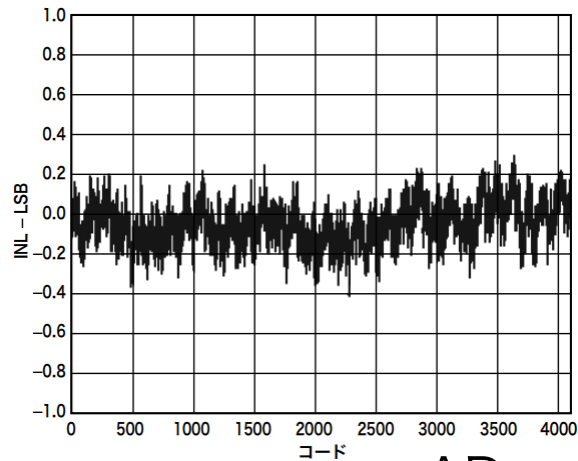
2. Sense nodes catch electrons

This talk theme
Future detector **XRPIX**

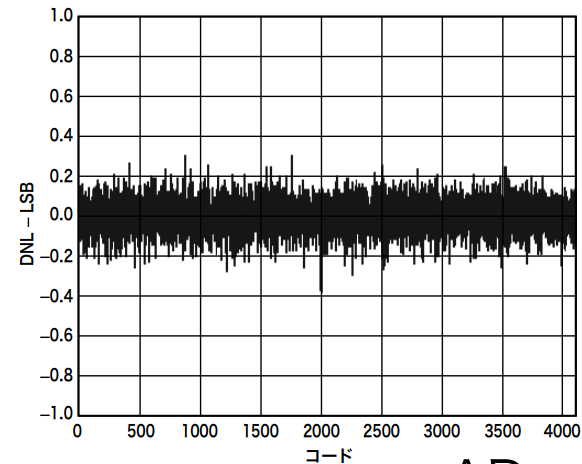


external ADC's INL & DNL

ADC : 12 bits

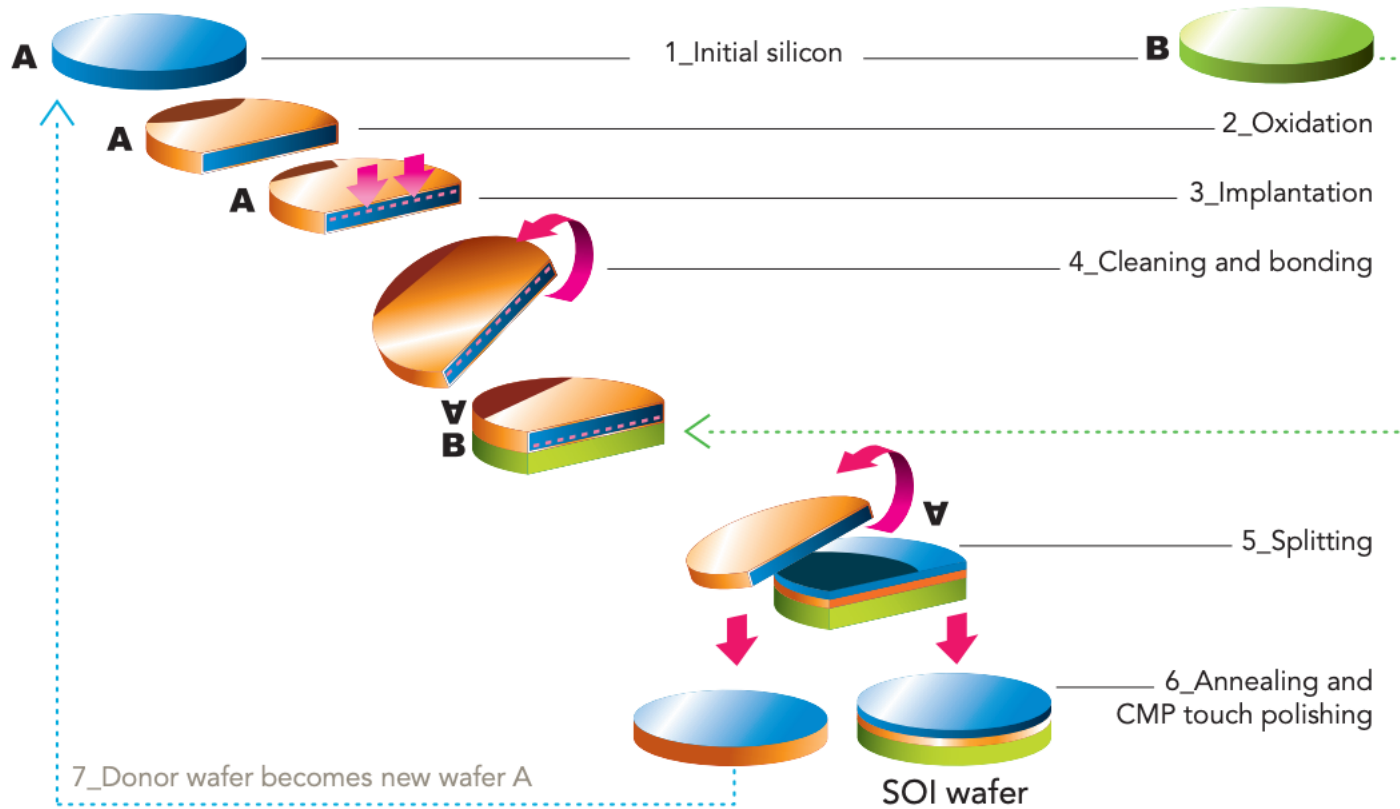


AD output



AD output

How to make SOI wafer



From SOITEC

<https://www.soitec.com/en/products/smart-cut>